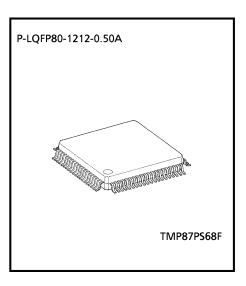
CMOS 8-Bit Microcontroller

## TMP87PS68DF

The 87PS68 is a One-Time PROM microcontroller with low-power 480 K bits electrically programmable read only memory for the 87CS68 system evaluation. The 87PS68 is pin compatible with the 87CS68. The operations possible with the 87CS68 can be performed by writing programs to PROM. The 87PS68 can write and verify in the same way as the TC571000D using an adaptor socket BM11105 and an EPROM programmer.

Part No.	ОТР	RAM	Package	OTP Adapter
TMP87PS68F	61184 bytes (60 Kbyte-256 byte)	2 K × 8-bit	P-LQFP80-1212-0.50A	BM11105



980910EBP1

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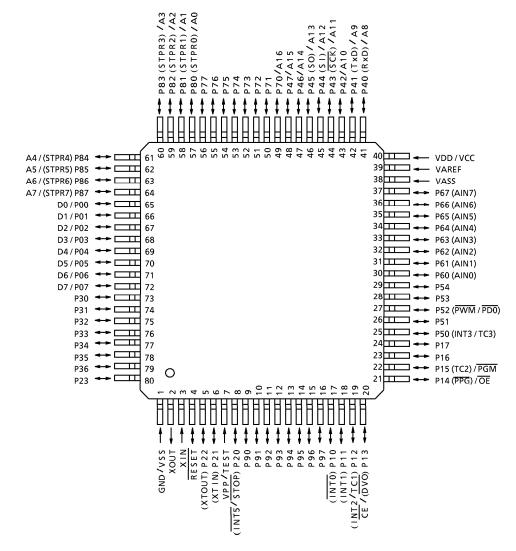
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3-68-109 1999-08-23

## Pin Assignments (Top View)

P-LQFP80-1212-0.50A



## **Pin Function**

The 87PS68 has two modes: MCU and PROM.

(1) MCU mode
In this mode, the 87PS68 is pin compatible with the 87CS68 (fix the TEST pin at low level.)

(2) PROM mode

Pin Name (PROM mode)	Input/Output	Functions	Pin Name (MCU mode)			
A16			P70			
A15 to A8	Input	PROM address inputs	P47 to P40			
A7 to A0			P87 to P80			
D7 to D0	I/O	PROM data input/outputs	P07 to P00			
CE		Chip enable signal input (active low)	P13			
ŌĒ	Input	Output enable signal input (active low)	P14			
PGM		Program mode signal input	P15			
VPP		+ 12.75 V / 5 V (Program supply voltage)	TEST			
vcc	Power supply	+6.25 V / 5 V	VDD			
GND		0 V	VSS			
P36 to P30						
P54 to P50		Pull up with resistance for input	processing			
P67 to P60		Pull-up with resistance for input processing.				
P77 to P72						
P11	I/O					
P21		PROM mode setting pin. Be fixed	l at high level.			
P71						
P17, P16, P12, P10 P22, P20		PROM and the action of the Residual And the American				
RESET		PROM mode setting pin. Be fixed at low level.				
XIN	Input					
хоит	Output	Connect an 8MHz oscillator to stabilize the internal state.				
VAREF	Downer supply	OVICND				
VASS	Power supply	0 V (GND)				

### **Operational Description**

The following explains the 87PS68 hardware configuration and operation. The configuration and functions of the 87PS68 are the same as 87CS68, except in that a one-time PROM is used instead of an on-chip mask ROM.

The 87PS68 is placed in the *single-clock* mode during reset. To use the dual-clock mode, the low-frequency oscillator should be turned on by executing [SET (SYSCR2). XTEN] instruction at the beginning of the program.

#### 1. Operating Mode

The 87PS68 has two modes: MCU and PROM.

#### 1.1 MCU Mode

The MCU mode is activated by fixing the TEST / VPP pin at low level.

In the MCU mode, operation is the same as with the 87CS68 (the TEST / VPP pin cannot be used open because it has no built-in pull-down resistance).

#### 1.1.1 Program Memory

The 87PS68 has a  $60K \times 8$ -bit (addresses  $1100_{H}$ -FFFF<sub>H</sub> in the MCU mode, addresses  $11100_{H}$ -1FFFF<sub>H</sub> in the PROM mode) of program memory (OTP).

When the 87PS68 is used as a system evaluation of the 87CS68, the data is written to the program storage area shown in Figure 1-1.

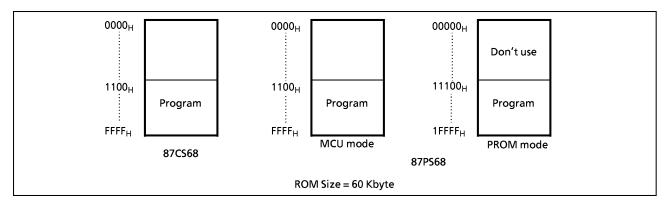


Figure 1.1 Program Memory Area

Note: Either write the data  $FF_H$  to the unused area or set the PROM programmer to access only the program storage area.

#### **Electrical Characteristics**

(1) 87PS68

Absolute Maximum Ratings  $(V_{SS} = 0 V)$ 

Parameter	Symbol	Conditions	Ratings	Unit	
Supply Voltage	$V_{DD}$		- 0.3 to 6.5	V	
Input Voltage	V <sub>IN</sub>		- 0.3 to V <sub>DD</sub> + 0.3	V	
Output Voltage	V <sub>OUT</sub>		- 0.3 to V <sub>DD</sub> + 0.3	V	
Output Current (Per 1pin)	I <sub>OUT1</sub>	Ports P0, P1, P2, P4, P5, P6, P7, P8, P9	3.2	mA	
	I <sub>OUT2</sub>	Port P3	30		
Output Compat (Tatal)	Σ l <sub>OUT1</sub>	Ports P0, P1, P2, P4, P5, P6, P7, P8, P9	160		
Output Current (Total)	Σ I <sub>OUT2</sub>	Port P3	120	mA	
Power Dissipation [Topr = 70°C]	PD		350	mW	
Soldering Temperature (time)	Tsld		260 (10 s)	°C	
Storage Temperature	Tstg		– 55 to 125	°C	
Operating Temperature	Topr		- 30 to 70	°C	

Note: The absolute maximum ratings are rated values which must not be exceeded during operation, even for an instant. Any one of the ratings must not be exceeded. If any absolute maximum rating is exceeded, a device may break down or its performance may be degraded, causing it to catch fire or explode resulting in injury to the user. Thus, when designing products which include this device, ensure that no absolute maximum rating value will ever be exceeded.

**Recommended Operating Conditions** 

 $(V_{SS} = 0 \text{ V}, \text{ Topr} = -30 \text{ to } 70^{\circ}\text{C})$ 

Parameter	Symbol	Pins	Conditions			Min		Max	Unit
			fc = 8 MHz	NORMAL1, 2 mode		4.5			
			TC = 8 IVIHZ	IDLE1, 2 mode	4.5				
			fc ≤ 4.2 MHz	NORMAL1, 2 mode					
Supply Voltage	$V_{DD}$		TC ≦ 4.2 IVIHZ	IDLE1, 2 mode		2.7		5.5	V
			fs =	SLOW mode	2.7				
			32.768 kHz	SLEEP mode					
			STOP mode		2.0				
	V <sub>IH1</sub>	Except hysteresis input	V <sub>DD</sub> ≥4.5 V V <sub>DD</sub> <4.5 V		ept hysteresis input $V_{DD} \times 0.70$		0		
Input High Voltage	V <sub>IH2</sub>	Hysteresis input			$V_{DD} \times 0.75$		$V_{DD}$	V	
	V <sub>IH3</sub>				$V_{DD} \times 0.90$				
	V <sub>IL1</sub>	Except hysteresis input	V <sub>DD</sub> ≥ 4.5 V					$V_{DD} \times 0.30$	
Input Low Voltage	$V_{IL2}$	Hysteresis input			0		$V_{DD} \times 0.25$	] v	
	V <sub>IL3</sub>		V <sub>I</sub>	<sub>DD</sub> <4.5 V	1			$V_{DD} \times 0.10$	
			45. 55.			fc	0.4	8.0	
	fc	VIN VOUT	V <sub>DD</sub> :	= 4.5 to 5.5 V	gear	fc/2	0.8	6.0	
Clock Frequency	10	XIN, XOUT	V <sub>DD</sub> = 2.7 to 5.5 V		ratio fc/4	fc/4	1.6	4.10	MHz
						fc/8	3.2	4.19	
	fs	XTIN, XTOUT				30.0		34.0	kHz

Note 1: The recommended operating Conditions for a device are operating Conditions under which it can be guaranteed that the device will operate as specified. If the device is used under operating Conditions other than the recommended operating Conditions (supply voltage, operating temperature range, specified AC/DC values etc.), malfunction may occur. Thus, when designing products which include this device, ensure that the recommended operating Conditions for the device are always adhered to.

Note2: Clock frequency fc: The supply voltage range of the conditions shows the value in NORMAL1, 2 modes and IDLE 1,2 modes.

#### D.C. Characteristics

 $(V_{SS} = 0 \text{ V}, \text{ Topr} = -30 \text{ to } 70 \text{ °C})$ 

Parameter	Symbol	Pins	Conditions	Min	Тур.	Max	Unit
Hysteresis Voltage	V <sub>HS</sub>	Hysteresis input		-	0.9	_	V
	I <sub>IN1</sub>	TEST					
Input Current	I <sub>IN2</sub>	Sink open drain port and tri-state port	V <sub>DD</sub> = 5.5 V V <sub>IN</sub> = 5.5 V / 0 V	_	-	± 2	μA
	I <sub>IN3</sub>	RESET, STOP	IIV				
Input Resistance	R <sub>IN2</sub>	RESET		100	220	450	kΩ
input kesistance	R <sub>IN</sub>	P8 pull-up resistor		30	70	150	K32
Output Leakage Current	I <sub>LO</sub>	Sink open drain port and tri-state port	$V_{DD} = 5.5 \text{ V}, V_{OUT} = 5.5 \text{ V}$	ı	_	2	μΑ
Output High Voltage	V <sub>OH2</sub>	Tri-state port	$V_{DD} = 4.5 \text{ V}, I_{OH} = -0.7 \text{ mA}$	4.1	_	_	<
Output Low Voltage	$V_{OL}$	Except XOUT and P3	$V_{DD} = 4.5 \text{ V}, I_{OL} = 1.6 \text{ mA}$	-	_	0.4	<
Output Low Current	I <sub>OL3</sub>	Port P3	$V_{DD} = 4.5 \text{ V}, V_{OL} = 1.0 \text{ V}$	-	20	_	mΑ
Supply Current in NORMAL 1, 2 mode			V <sub>DD</sub> = 5.5 V V <sub>IN</sub> = 5.3 V / 0.2 V	_	9	12	
Supply Currnt in IDLE 1, 2 mode			fc = 8 MHz fs = 32.768 kHz	_	4.5	6.5	
Supply Currnt in NORMAL 1, 2 mode	y Currnt in		$V_{DD} = 3.0 \text{ V}$ $V_{IN} = 2.8 \text{ V} / 0.2 \text{ V}$	-	T.B.D	T.B.D	mA
Supply Currnt in IDLE 1, 2 mode			fc = 4.2 MHz fs = 32.768 kHz	_	T.B.D	T.B.D	
Supply Current in SLOW mode			V <sub>DD</sub> = 3.0 V	_	30	60	μA
Supply Current in SLEEP mode	V <sub>IN</sub> = 2.8 V / 0.2 V fs = 32.768 kHz		-	15	30	μΑ	
Supply Current in STOP mode			V <sub>DD</sub> = 5.5 V V <sub>IN</sub> = 5.3 V / 0.2 V	-	0.5	10	μA

Note 1: Typical values show those at  $Topr = 25^{\circ}C$ ,  $V_{DD} = 5V$ . Note 2: Input current: The current through pull-up or pull-down resistor is not included.

### A / D Conversion Characteristics

 $(V_{SS} = 0 \text{ V}, V_{DD} = 4.5 \text{ to } 5.5 \text{ V}, \text{Topr} = -30 \text{ to } 70^{\circ}\text{C})$ 

Parameter	Symbol	Conditions	Min	Тур.	Max	Unit	
Analog Reference Voltage	V <sub>AREF</sub>	V > 25V	2.7	_	V <sub>DD</sub>	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	
	V <sub>ASS</sub>	$V_{AREF} - V_{ASS} \ge 2.5V$	V <sub>SS</sub>	_	1.5	- V	
Analog Input Voltage	V <sub>AIN</sub>	$V_{DD} = V_{AREF} = 5.0 \text{ V}$ $V_{SS} = V_{ASS} = 0.0 \text{ V}$	V <sub>ASS</sub>	_	V <sub>AREF</sub>	V	
Analog Supply Current	I <sub>REF</sub>	$V_{AREF} = 5.5 \text{ V}, \ V_{ASS} = 0.0 \text{ V}$	_	0.5	1.0	V	
Nonlinearity Error		V 274.55V	_	_	± 1	4	
Zero Point Error		V <sub>DD</sub> = 2.7 to 5.5 V V <sub>SS</sub> = 0.0 V	_	_	± 1	mA	
Full Scale Error		V <sub>AREF</sub> = 2.700 V, 5.000 V	_	_	± 1	LCD	
Total Error		V <sub>ASS</sub> = 0.000 V		_	± 2	LSB	

Note: Total Error = total number of each type error excluding guantization error

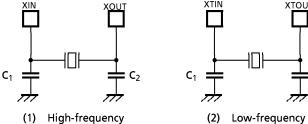
### A.C. Characteristics

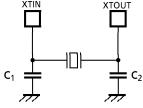
(V<sub>SS</sub> = 0 V,  $V_{DD}$  = 4.5 to 5.5 V, Topr = -30 to 70 °C)

Parameter	Symbol			Max	Unit	
Machine Cycle Time		In NORMAL1, 2 mode (gear ratio)	0 5 (1(1)		40 (4 (0)	
	t <sub>cy</sub>	In IDLE1, 2 mode (gear ratio)	0.5 (1/1)	_	10 (1/8)	
		In SLOW mode	117.6		133.3	$\mu$ S
		In SLEEP mode	117.6			
High Level Clock Pulse Width	t <sub>WCH</sub>	For external clock operation (XIN input)				
Low Level Clock Pulse Width	t <sub>WCL</sub>	fc = 8 MHz	50	_	_	ns
High Level Clock Pulse Width	t <sub>WSH</sub>	For external clock operation (XTIN input)	14.7		_	
Low Level Clock Pulse Width	t <sub>WSL</sub>	fs = 32.768 kHz	14.7	_		μS

## **Recommended Oscillating Condition**

Parameter Oscillator		Francisco	Pagaman dad Ossillatar	Recommended Condition		
Parameter	Oscillator	rrequency	Frequency Recommended Oscillator		C <sub>2</sub>	
		8 MHz	KYOCERA KBR8.0M			
High-frequency	Ceramic Resonator		KYOCERA KBR4.0MS	30 pF	30 pF	
		4 MHz	MURATA CSA4.00MG			
Low-frequency	Crystal Oscillator	32.768 kHz	NDK MX-38T	15 pF	15 pF	





Note: When it is used in high electrical field, an electrical shield of the package is recommended to retain normal operations

Note: To obtain an accurate oscillating frequency the condenser capacity must be adjusted on the sct.

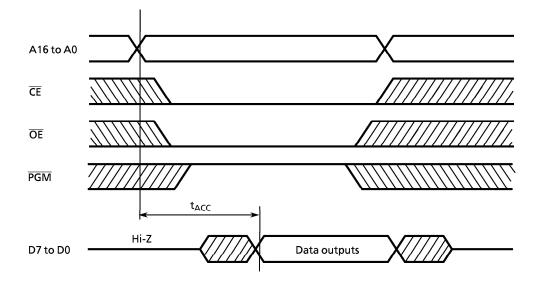
D.C./A.C. Characteristics (PROM mode)

 $(V_{SS} = 0 V)$ 

# (1) Read Operation

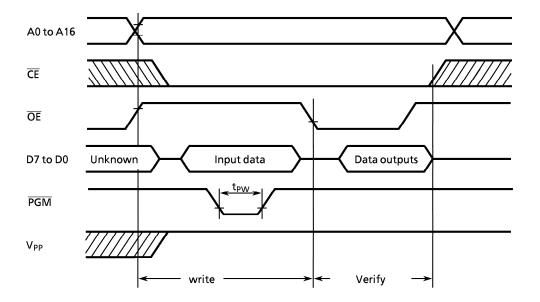
Parameter	Symbol	Conditions	Min	Тур.	Max	Unit
Input High Voltage	V <sub>IH4</sub>		2.2	_	V <sub>CC</sub>	V
Input Low Voltage	V <sub>IL4</sub>		0	_	0.8	V
Power Supply Voltage	V <sub>CC</sub>		4.75	5.0	5.25	v
Program Power Supply Voltage	V <sub>PP</sub>		4.75	5.0	5.25	\
Address Access Time	t <sub>ACC</sub>	V <sub>CC</sub> = 5.0 ± 0.25 V	_	1.5tcyc + 300	1	ns

Note: tcyc = 500 ns at 8 MHz



### (2) High-Speed Programming Operation (Topr = $25 \pm 5$ °C)

Parameter	Symbol	Conditions	Min	Тур.	Max	Unit
Input High Voltage	V <sub>IH4</sub>		2.2	-	V <sub>CC</sub>	V
Input Low Voltage	V <sub>IL4</sub>		0	_	0.8	V
Power Supply Voltage	V <sub>CC</sub>		6.0	6.25	6.5	V
Program Power Supply Voltage	V <sub>PP</sub>		12.5	12.75	13.0	V
Initial Program Pulse Width	t <sub>PW</sub>	V <sub>CC</sub> = 6.0 V	0.095	0.1	0.105	ms



Note1: When  $V_{cc}$  power supply is turned on or after,  $V_{pp}$  must be increased. When  $V_{cc}$  power supply is turned off or before,  $V_{pp}$  must be increased.

Note2: The device must not be set to the EPROM programmer or picked op from it under applying the program voltage (12.5 V  $\pm$  0.5 V = V) to the  $V_{pp}$  pin as the device is damaged.

Note3: Be sure to execute the recommended programing mode with the recommended programing adaptor. If a mode or an adaptor except the above, the misoperation sometimes occurs.